PATENT SERIAL 11/183800 NUMLER SUBCLASS 49 SHUNPEI YAMAZAKI, TOKYO, JAPAN; HONGYONG ZHANG, KANAGAWA, JAPAN; NAOTO KUSUMOTO, KANAGAWA, JAPAN, YASUHIKO TAKEMURA, KANAGAWA, JAPAN. \*\*CONTINUING DATA\*\* THIS APPLN IS A CON OF 07/852,517 03/17/92 U.S. Palent No. 5296, 405 07/933,718 8/24/92 U.S. Putent No 5,171,710 07/520,998 07/251,940 06/891,791 5/9/90 U.S. Patent No. 4, 986, 213. IS A CON OF WHICH 8/1196 'ABN \*FOREIGN/PCT APPLICATIONS\*\*\*\* VERIFIED' FED REP GERMANY/ 03/18/91 JAPAN The term of this patent shall not extend beyond the excircular cate of Pat. No. 5 STATE OR SHEETS COUNTRY DRWGS. FILED STXBEY, FRIEDMAN, LEEDOM & FERGUSON 2010 CORFORATE RIDGE SUITE 600 MCLEAN, VA 22102 SEMICONDUCTOR MATERIAL AND METHOD FOR FORMING THE SAME AND THIN FILM TRANSISTOR U.S. DEPT. of COMM. Pat. & TM Office PTO-436L (rpv. 10-78) PARTS OF APPLICATION A Primary Examiner ISSUE BATCH NUMBER Primary Examiner PREPARED FOR ISSUE WARNING: The information disclosed herein may be restricted. Unauthorized disclosure may be prohibited by the United States Code Title 35, Sections 122, 181 and 368. Possession outside the US Patent & Trademark Office is restricted to authorized employees and contracters only: Formal Drawings (

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